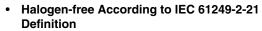


ZVP3306FTA-VB Datasheet P-Channel 60 V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|---------------------|-------------------------------|-------------------------|---------------------|--|--|
| V _{DS} (V) | $R_{DS(on)}(\Omega)$ | V _{GS(th)} (V) | I _D (mA) | | |
| - 60 | 3 at V _{GS} = - 10 V | - 1 to - 3 | -500 | | |

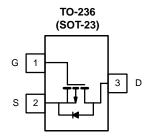
FEATURES

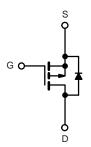




RoHS

- TrenchFET[®] Power MOSFET
- High-Side Switching
- Low On-Resistance: 3 $\,\Omega\,$
- Low Threshold: 2 V (typ.)
- Fast Swtiching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- Compliant to RoHS Directive 2002/95/EC





P-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted | | | | | |
|---|-------------------------|----------------------------------|-------------|----------|--|
| Parameter | | Symbol | Limit | Unit | |
| Drain-Source Voltage | | V _{DS} | - 60 | V | |
| Gate-Source Voltage | | V _{GS} | ± 20 | v | |
| Outline Date Outline | T _A = 25 °C | 1 | - 500 | mA | |
| Continuous Drain Current ^a | T _A = 100 °C | 'D | - 350 | | |
| Pulsed Drain Current ^b | | I _{DM} | -1500 | | |
| Davier Dissingtion 8 | T _A = 25 °C | P _D | 460 | mW | |
| Power Dissipation ^a | T _A = 100 °C | | 240 | 11100 | |
| Maximum Junction-to-Ambient ^a | • | R _{thJA} | 350 | °C/W | |
| Operating Junction and Storage Temperature Range | | T _{J,} T _{stg} | - 55 to 150 | °C | |

Notes:

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

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| | | | Limits | | | | |
|---|---------------------|--|----------------------------------|-------------------|-------|-------|--|
| Parameter | Symbol | Test Conditions | Min. | Typ. ^a | Max. | Unit | |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A}$ | - 60 | | | V | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$ | - 1 | | - 3 |] v | |
| | | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ± 10 | μΑ | |
| Cata Bady Loakaga | | V _{DS} = 0 V, V _{GS} = ± 10 V | | | ± 200 | ± 200 | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 \text{ °C}$ | | | ± 500 | nA | |
| | | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$ | | | ± 100 | | |
| Zava Cata Valtaga Dvain Curvent | , | V _{DS} = - 60 V, V _{GS} = 0 V | - 25 | | - 25 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 85 °C | as = 0 V, T _J = 85 °C | | - 250 | | |
| On-State Drain Current ^a | | V _{GS} = - 10 V, V _{DS} = - 4.5 V | - 50 | | | mA | |
| | I _{D(on)} | V _{GS} = - 10 V, V _{DS} = - 10 V | - 600 | | | | |
| Drain-Source On-Resistance ^a | R _{DS(on)} | V _{GS} = - 4.5 V, I _D = - 25 mA | | 4 | | Ω | |
| | | V _{GS} = - 10 V, I _D = - 100 mA | | 3 | | | |
| | | V _{GS} = - 10 V, I _D = - 100 mA, T _J =125 °C | | 9 | | | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = - 10 V, I _D = - 100 mA | 80 | | | mS | |
| Diode Forward Voltage | V _{SD} | I _S = - 100 mA, V _{GS} = 0 V | | | - 1.4 | V | |
| Dynamic | | | | | | | |
| Total Gate Charge | Qg | | | 2.0 | | | |
| Gate-Source Charge | Q _{gs} | $V_{DS} = -30 \text{ V}, V_{GS} = -15 \text{ V}$ $I_{D} \cong -100 \text{ mA}$ | | 1.2 | | nC | |
| Gate-Drain Charge | Q _{gd} | 10 = 100 mA | | 0.8 | | | |
| Input Capacitance | C _{iss} | | | 23 | | | |
| Output Capacitance | C _{oss} | $V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz | | 10 | | рF | |
| Reverse Transfer Capacitance | C _{rss} | 1 – 1 1011 12 | | 5 | | 1 | |
| Switching ^b | | | | | | | |
| Turn-On Time | t _{d(on)} | $V_{DD} = -25 \text{ V}, R_{L} = 150 \Omega$ | | 20 | | ne | |
| Turn-Off Time | t _{d(off)} | $I_D \cong$ - 200 mA, $V_{GEN} =$ - 10 V, $R_g =$ 10 Ω | | 35 | | ns | |

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

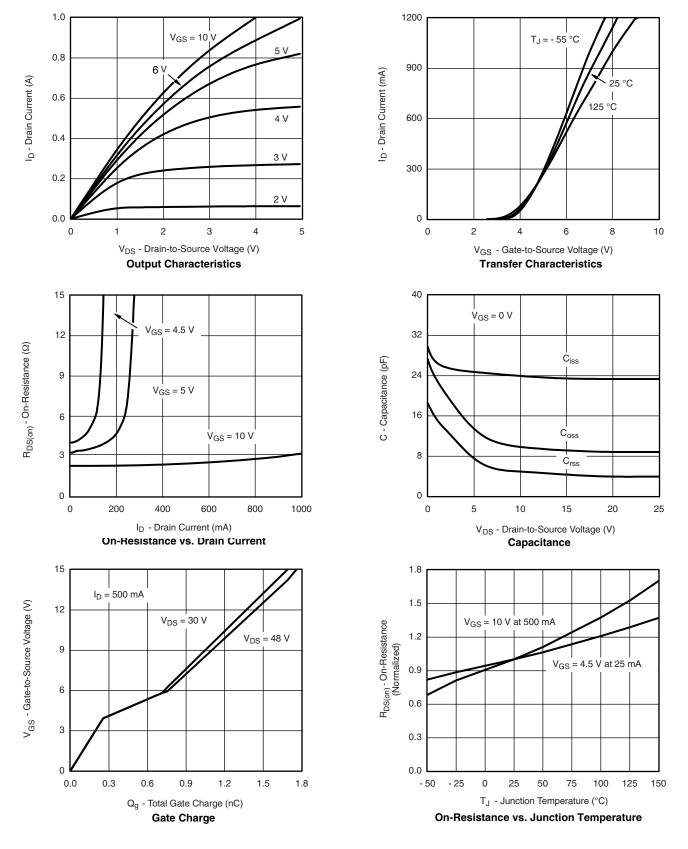
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a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.

b. Switching time is essentially independent of operating temperature.



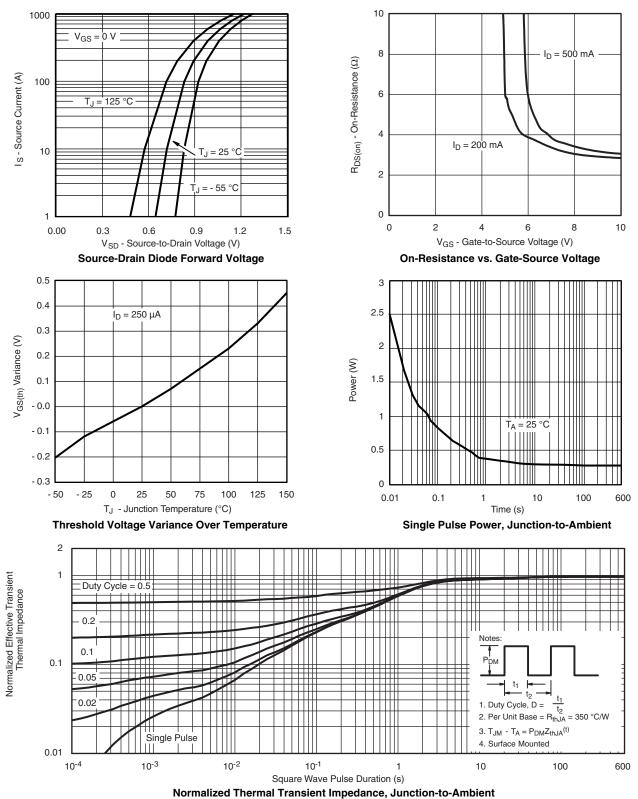
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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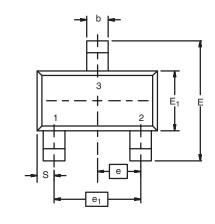
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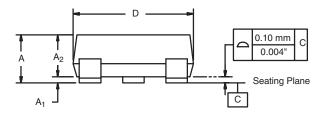


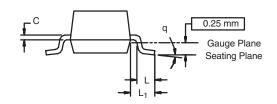
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SOT-23 (TO-236): 3-LEAD







| Dim | MILLIMETERS | | INCHES | | |
|------------------------|-------------|---------------------|-----------|-------|--|
| | Min | Max | Min | Max | |
| Α | 0.89 | 1.12 | 0.035 | 0.044 | |
| A ₁ | 0.01 | 0.10 | 0.0004 | 0.004 | |
| A ₂ | 0.88 | 1.02 | 0.0346 | 0.040 | |
| b | 0.35 | 0.50 | 0.014 | 0.020 | |
| С | 0.085 | 0.18 | 0.003 | 0.007 | |
| D | 2.80 | 3.04 | 0.110 | 0.120 | |
| E | 2.10 | 2.64 | 0.083 | 0.104 | |
| E ₁ | 1.20 | 1.40 | 0.047 | 0.055 | |
| е | 0.9 | 0.95 BSC 0.0374 Ref | | 4 Ref | |
| e ₁ | 1.9 | 0 BSC | 0.074 | 8 Ref | |
| L | 0.40 | 0.60 | 0.016 | 0.024 | |
| L ₁ | 0.64 Ref | | 0.025 Ref | | |
| S | 0.50 Ref | | 0.020 Ref | | |
| q | 3° | 8° | 3° | 8° | |
| FCN: S-03946-Rev K 09- | Jul-01 | • | | | |

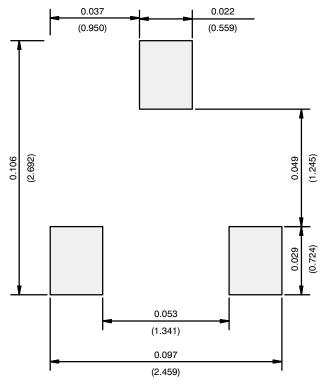
ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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